

View Online at <https://aerobasegroup.com/nsn/5961-01-070-2815>

Inclosure Material:

Ceramic all semiconductor device diode

Overall Length:

0.215 inches all semiconductor device diode

Overall Diameter:

0.120 inches all semiconductor device diode

Function For Which Designed:

Varactor diode

Component Function Relationship:

Matched

Component Name And Quantity:

6 semiconductor device diode

Mounting Method:

Terminal all semiconductor device diode

Field Force Effect Type:

Electrostatic charge

Semiconductor Material:

Silicon all semiconductor device diode

Voltage Rating In Volts Per Characteristic:

42.0 reverse breakdown voltage, dc all semiconductor device diode

Power Rating Per Characteristic:

2.0 watts small-signal input power, common-collector absolute all semiconductor device diode

Maximum Operating Temperature Per Measurement Point:

175.0 degrees celsius junction all semiconductor device diode

Test Data Document:

13499-922-6104 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

2 connector, coaxial all semiconductor device diode

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fig:

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